Solution brief

CoolGaN™ 600 V and GaN EiceDRIVER™
Cutting-edge performance with excellent reliability

The next essential step towards an energy-efficient world lies in the use of new materials and technologies. Wide bandgap semiconductors enable greater power efficiency, smaller size, lighter weight, lower cost, or all together.

Key advantages of CoolGaN™ 600 V solution
› The enhancement mode (e-mode) concept - the most robust and performing solution in the market
› Industry-leading performance with the best figures-of-merit (FOM), enabling rugged and reliable system designs at an attractive overall system cost
› Ten times higher breakdown field and a double electron mobility, compared to silicon
› Ten times lower output and gate charge than silicon, enabling high frequency operations
› Enabling hard switching in half-bridge topologies with an almost zero reverse recovery charge
› Most reliable GaN solution in the market ensured through Infineon’s pioneering qualification concept
› A predicted lifetime of more than 15 years with a failure rate below 1 FIT
› Perfect choice for a broad variety of applications such as server, telecom, hyperscale datacenters, adapters/chargers, wireless charging, SMPS and many others

Driving CoolGaN™ HEMTs with GaN EiceDRIVER™ ICs
› Positive and negative gate drive current enabling fast switching
› Firmly holding gate drive voltage at zero when GaN switch is intended to be off, protects against spurious turn-on
› Configurable and constant GaN switching slew-rates over a wide range of switching frequencies and duty cycles, results in robust and efficient GaN operation and short time-to-market
› Integrated galvanic isolation
  – Robust operation in hard-switching applications
  – Mandatory where safety is required

System features
› The most reliable GaN-based solution, delivering highest performance amongst all available GaN devices
› Manufacturing expertise throughout the entire supply chain
› Global application design support
› Broad portfolio including switches and drivers

System benefits
› Perfect choice for high frequency and high power density applications
› Industry-leading solution for target applications
› GaN EiceDRIVER™ ICs for excellent robustness and efficiency
› High quality volume supply that enables faster time-to-market
› Reduced BOM costs and overall system cost

www.infineon.com/gan
www.infineon.com/gan-eicedriver
High efficiency GaN switched mode power supply (SMPS)

Product portfolio CoolGaN™ 600 V e-mode HEMTs

<table>
<thead>
<tr>
<th>$R_{\text{on}}$ max. (mΩ)</th>
<th>DSO-20-85 Bottom-side cooling</th>
<th>DSO-20-87 Top-side cooling</th>
<th>HSOF-8-3 TO-leadless</th>
<th>LSON-8-1 DFN 8x8</th>
</tr>
</thead>
<tbody>
<tr>
<td>35</td>
<td>IGO60R035D1**</td>
<td>IGO60R035D1**</td>
<td>IGT60R035D1**</td>
<td>IGLD60R070D1</td>
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<tr>
<td>70</td>
<td>IGO60R070D1</td>
<td>IGT60R070D1</td>
<td>IGT60R190D1*</td>
<td>IGLD60R190D1</td>
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<tr>
<td>190</td>
<td></td>
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* Standard ** Coming soon

Product portfolio GaN EiceDRIVER™

<table>
<thead>
<tr>
<th>Package</th>
<th>13-pin LGA 5x5 mm</th>
<th>16-pin DSO 150 mil</th>
<th>16-pin DSO 300 mil</th>
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</thead>
<tbody>
<tr>
<td>Product</td>
<td>1EDF5673K</td>
<td>1EDF5673F</td>
<td>1EDS5663H</td>
</tr>
<tr>
<td>Isolation (input to output)</td>
<td>$V_{\text{oc}} = 1.5 \text{ kV}_{\text{ac}}$</td>
<td>$V_{\text{oc}} = 1.5 \text{ kV}_{\text{dc}}$</td>
<td>$V_{\text{oc}} = 8 \text{ kV}_{\text{dc}}$ (VDE0884-10)</td>
</tr>
<tr>
<td>Source/sink output resistance</td>
<td>0.85 Ω / 0.35 Ω</td>
<td>0.85 Ω / 0.35 Ω</td>
<td>0.85 Ω / 0.35 Ω</td>
</tr>
<tr>
<td>UVLO</td>
<td>4.5 V / 5.0 V</td>
<td>4.5 V / 5.0 V</td>
<td>4.5 V / 5.0 V</td>
</tr>
</tbody>
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